



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _(BR) DSS	R _{DS(ON)} Max	I _D Max T _A = +25°C
30V	50mΩ @ V _{GS} = 10V	3.6A
	70mΩ @ V _{GS} = 4.5V	2.8A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Battery Charging
- Power Management Functions
- DC-DC Converters
- Portable Power Adaptors

Features and Benefits

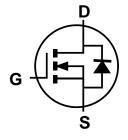
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



Top View







D

Pin Out

Ordering Information (Note 4)

Part Number	Case	Packaging
DMG3406L-7	SOT23	3000/Tape & Reel
DMG3406L-13	SOT23	10000/Tape & Reel

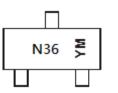
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



N36 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key

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Year	2014	4	2015		2016	20	17	2018		2019	2	2020
Code	В		С		D	E	Ξ	F		G		Н
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) $V_{GS} = 10V$ State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		ID	3.6 2.9	A	
Pulsed Drain Current (Note 6) (Pulse width ≤10µ	cle ≤1%)	I _{DM}	30	А	
Maximum Body Diode Forward Current (Note 6)	Is	1.4	А		

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	0.77	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R _{eja}	164	°C/W
Power Dissipation (Note 6)	PD	1.4	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6)	R _{eja}	90	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

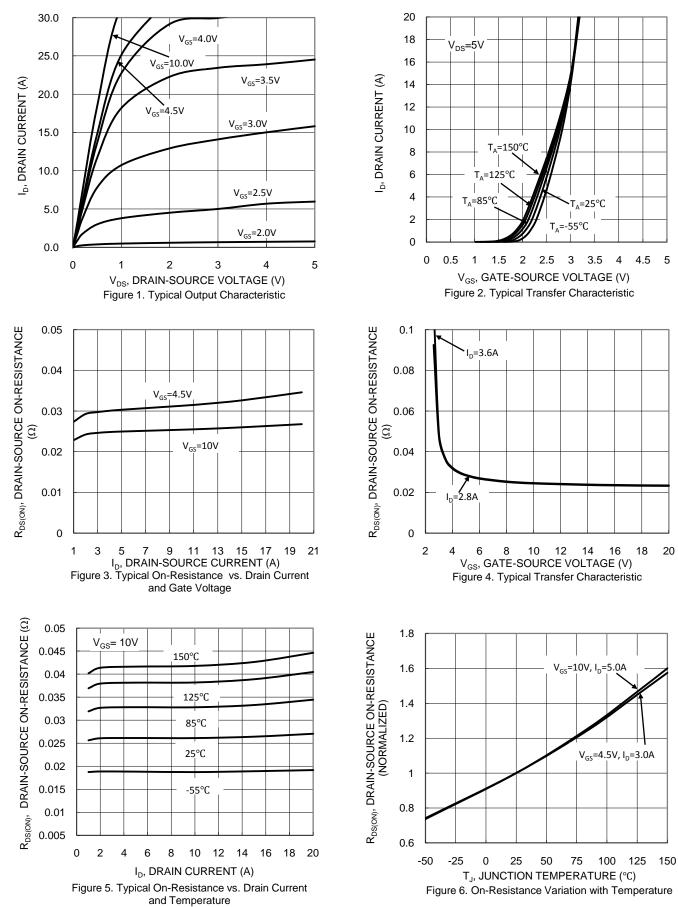
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	30			V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	_	1.0	μA	V_{DS} = 30V, V_{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1.0		2.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	P	_	25	50	mΩ	$V_{GS} = 10V, I_D = 3.6A$	
Static Drain-Source On-Resistance	R _{DS (ON)}		31	70	mΩ	$V_{GS} = 4.5V, I_D = 2.8A$	
Diode Forward Voltage	V _{SD}	_	0.75	1.0	V	$V_{GS} = 0V, I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)						-	
Input Capacitance	C _{iss}		495		pF		
Output Capacitance	C _{oss}	_	50	_	pF	$V_{DS} = 15V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	43		pF		
Gate Resistance	Rg	_	2.0		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge ($V_{GS} = 4.5V$)	Qg	_	5.3	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	11.2		nC	V _{DS} = 15V. I _D = 3.6A	
Gate-Source Charge	Q _{gs}	_	1.2	_	nC	$V_{DS} = 15V, I_D = 3.0A$	
Gate-Drain Charge	Q _{gd}	_	1.9		nC		
Turn-On Delay Time	t _{D(ON)}		2.3		ns		
Turn-On Rise Time	t _R		3.3		ns	$V_{DD} = 15V, V_{GS} = 10V,$	
Turn-Off Delay Time	t _{D(OFF)}		10.3	_	ns	$R_L = 2.2\Omega, R_G = 3\Omega$	
Turn-Off Fall Time	t _F	_	2.3		ns		

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Notes: Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1 inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

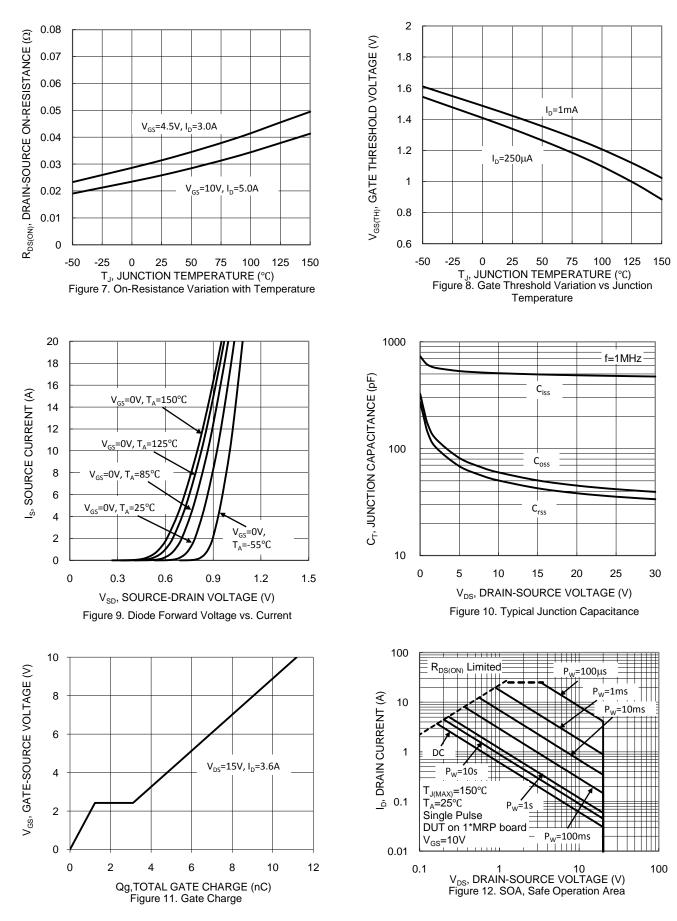




NEW PRODUCT

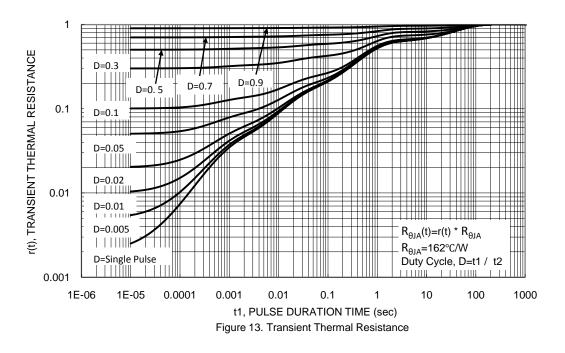
DMG3406L Document number: DS37639 Rev. 2 - 2





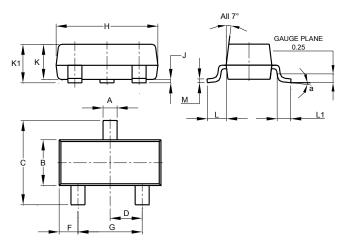
DMG3406L Document number: DS37639 Rev. 2 - 2 January 2015 © Diodes Incorporated





Package Outline Dimensions

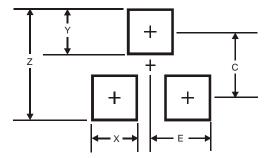
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
H	2.80	3.00	2.90					
J	0.013	0.10	0.05					
κ	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
α	8°							
All	All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35

NEW PRODUCT



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